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# 2N5551 / MMBT5551 NPN General-Purpose Amplifier

## Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers.



## MMBT5551



## Ordering Information<sup>(1)</sup>

Part Number	Top Mark	Package	Packing Method	
2N5551TA	5551	TO-92 3L	Ammo	
2N5551TFR	5551	TO-92 3L	Tape and Reel	
2N5551TF	5551	TO-92 3L	Tape and Reel	
2N5551BU	5551	TO-92 3L	Bulk	
MMBT5551	3S	SOT-23 3L	Tape and Reel	

### Note:

1. Suffix "-C" means Center Collector in 2N5551 (1. Emitter 2. Collector 3. Base) Suffix "-Y" means  $h_{FE}$  180~240 in 2N5551 (Test condition:  $I_C$  = 10 mA,  $V_{CE}$  = 5.0 V) June 2013

## Absolute Maximum Ratings<sup>(2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V
V <sub>CBO</sub>	Collector-Base Voltage	180	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ι <sub>C</sub>	Collector current - Continuous	600	mA
T <sub>J</sub> , T <sub>stg</sub> <sup>(2)</sup>	Junction and Storage Temperature	-55 to +150	°C

Notes:

- 2. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- 3. These ratings are based on a maximum junction temperature of 150 °C.

These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

## **Thermal Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter –	Maximum		Units	
		2N5551	MMBT5551	Units	
PD	Total Device Dissipation	625	350	mW	
۲D	Derate above 25°C	5.0	2.8	mW/°C	
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3		°C/W	
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	357	°C/W	

Symbol	at T <sub>A</sub> = 25°C unless otherwise noted. Parameter	Test Condition	Min.	Max.	Units
Off Charao				Max.	Units
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	160		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, \ I_{\rm E} = 0$	180		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \mu {\rm A},  I_{\rm C} = 0$	6.0		V
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0$		50	nA
		$V_{CB} = 120 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C}$		50	μA
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 4.0 \text{ V}, \text{ I}_{C} = 0$		50	nA
On Charac	cteristics			•	
		I <sub>C</sub> = 1.0 mA, V <sub>CE</sub> = 5.0 V	80		
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V	80	250	
		I <sub>C</sub> = 50 mA, V <sub>CE</sub> = 5.0 V	30		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA		0.15	V
		I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA		0.20	V
V <sub>BE(sat)</sub>	Ross Emitter On Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA		1.0	V
	Base-Emitter On Voltage	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA		1.0	V
Small-Sig	nal Characteristics				
f <sub>T</sub>	Current Gain Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100 MHz	100		MHz
C <sub>obo</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz		6.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{BE} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$		20	pF
H <sub>fe</sub>	Small-Signal Current Gain	$I_{C}$ = 1.0 mA, $V_{CE}$ = 10 V, f = 1.0 kHz	50	250	
NF	Noise Figure	$I_{C}$ = 250 μA, V <sub>CE</sub> = 5.0 V, R <sub>S</sub> =1.0 kΩ, f=10 Hz to 15.7 kHz		8.0	dB

### Note:

4. PCB board size FR-4 76 x 114 x 0.6 T mm<sup>3</sup> (3.0 inch  $\times$  4.5 inch  $\times$  0.062 inch) with minimum land pattern size.



75°C

100

T. = 75°C

100

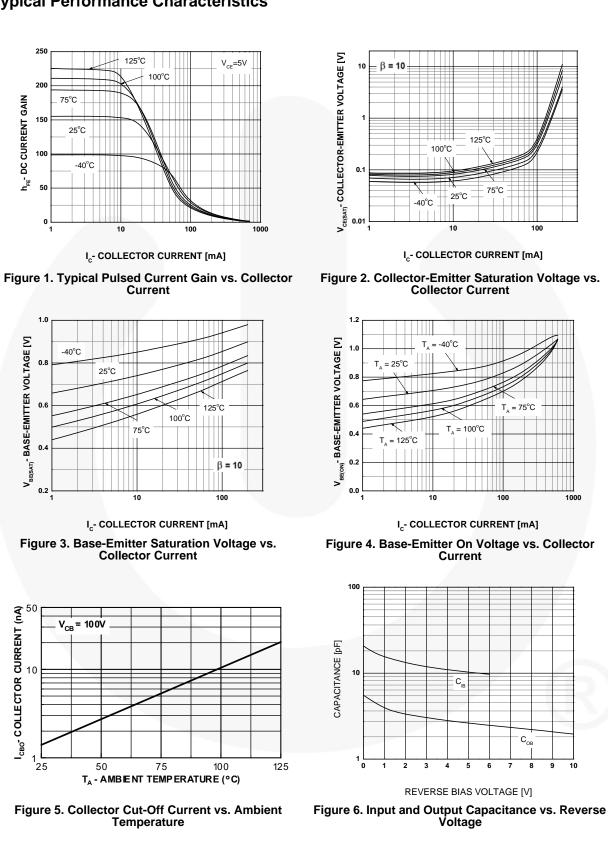
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8 9 10

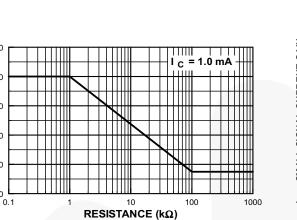
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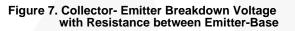
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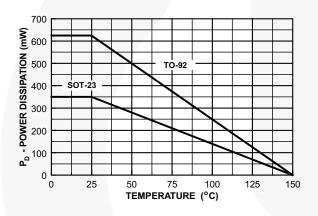


## **Typical Performance Characteristics**



Typical Performance Characteristics (Continued)







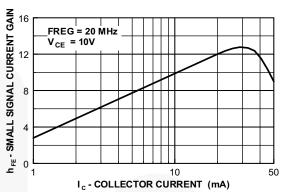
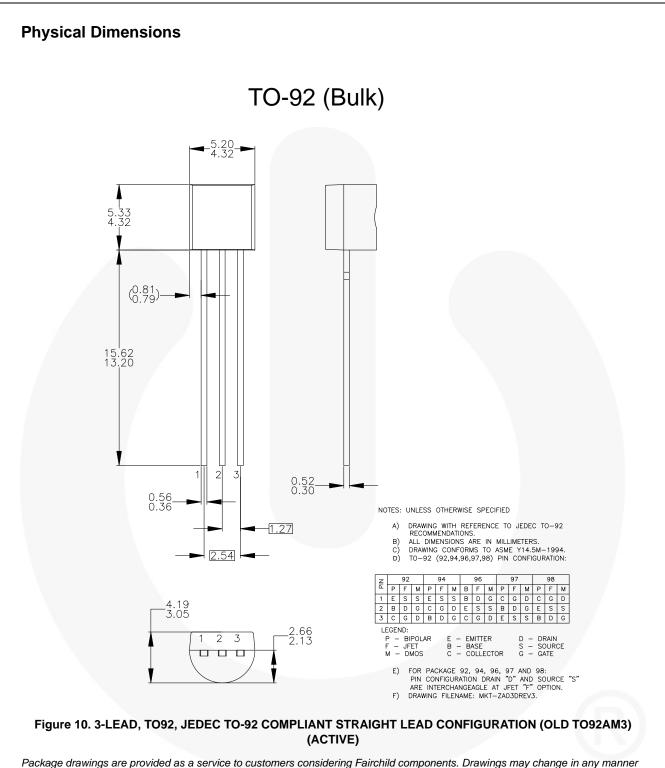


Figure 8. Small Signal Current Gain vs. Collector Current



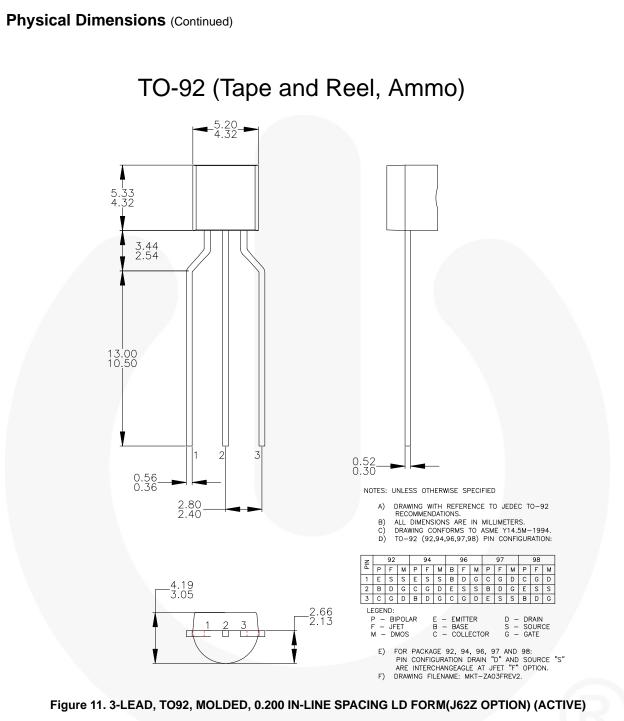
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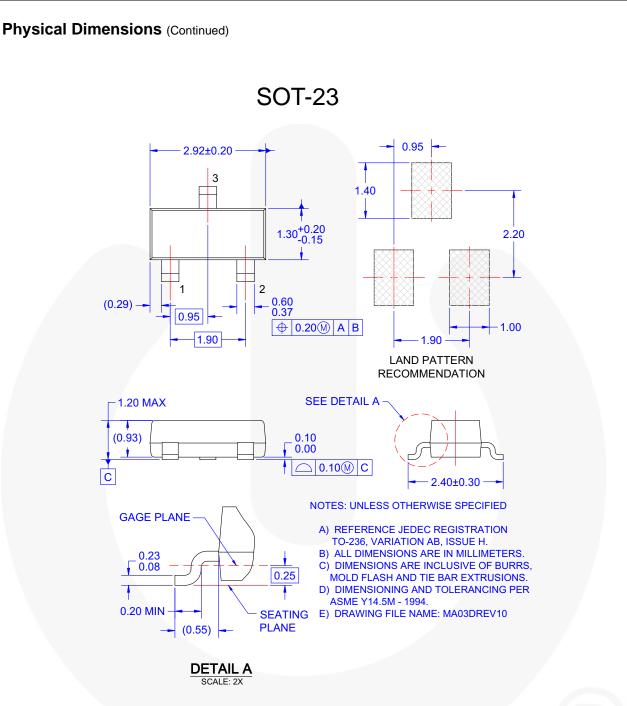


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#### Figure 12. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE (ACTIVE)

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